

MacMic Science & Technology Co., Ltd.

Add Ö

			Unit
			mA
			mA
			nA
			μC
			nF
			pF
			ns
			ns
			ns
			ns
		370	ns
t_f	Fall Time	T_J	ns
		70	ns

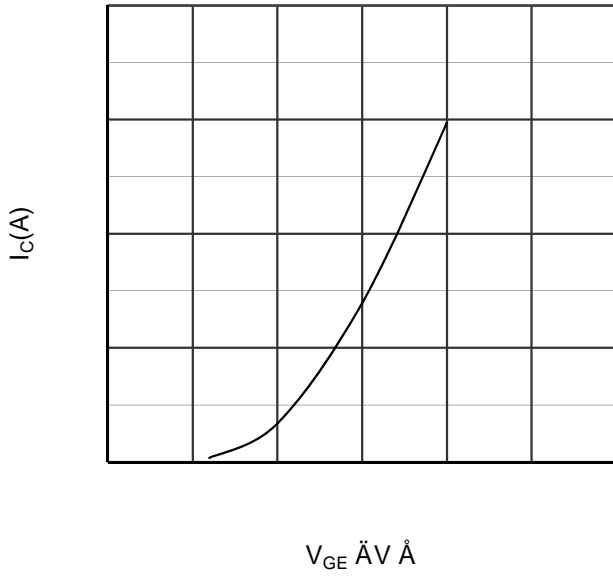


Figure 3. Typical Transfer characteristics IGBT-inverter

$E_{on} E_{off} \text{ (mJ)}$

$R_g \text{ \AA} \text{ \AA}$

Figure 4. Switching Energy vs Gate Resistor IGBT-inverter

V_F

Figure 14. Circuit DT5jfam
